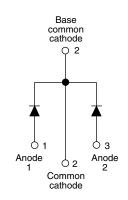




Vishay Semiconductors

Schottky Rectifier, 2 x 30 A

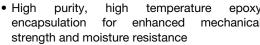


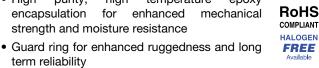


PRODUCT SUMMARY					
Package	TO-247AC				
I _{F(AV)}	2 x 30 A				
V _R	100 V				
V _F at I _F	0.64 V				
I _{RM} max.	25 mA at 125 °C				
T _J max.	175 °C				
Diode variation	Common cathode				
E _{AS}	15 mJ				

FEATURES

- 175 °C T_J operation
- · Low forward voltage drop
- High frequency operation





- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified according to JEDEC-JESD47
- Halogen-free according to IEC 61249-2-21 definition (-N3 only)

DESCRIPTION

The VS-63CPQ100G... center tap Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I _{F(AV)}	Rectangular waveform	60	A			
V_{RRM}		100	V			
I _{FSM}	$t_p = 5 \mu s sine$	2200	Α			
V _F	30 Apk, T _J = 125 °C (per leg)	0.64	V			
T _J	Range	- 55 to 175	°C			

VOLTAGE RATINGS						
PARAMETER	SYMBOL	VS-63CPQ100PbF	VS-63CPQ100-N3	UNITS		
Maximum DC reverse voltage	V _R	100	100	V		
Maximum working peak reverse voltage	V_{RWM}	100	100	V		

ABSOLUTE MAXIMUM RATINGS							
PARAMETER		SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum average forward current	per leg		50 % duty cycle at T _C = 153 °C, rectangular waveform			30	
See fig. 5	per device	I _{F(AV)}			60	Α	
' '	Maximum peak one cycle non-repetitive		5 μs sine or 3 μs rect. pulse	Following any rated load condition and with	2200		
Surge current per leg See fig. 7		I _{FSM}	10 ms sine or 6 ms rect. pulse	rated V _{RRM} applied	410		
Non-repetitive avalanche energy per leg		E _{AS}	$T_J = 25 ^{\circ}\text{C}, I_{AS} = 1 \text{A}, L = 30 \text{mH}$		15	mJ	
Repetitive avalanche current per leg		I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T_J maximum $V_A = 1.5$ x V_R typical		1	Α	



VS-63CPQ100GPbF, VS-63CPQ100G-N3

Vishay Semiconductors

ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
		30 A	T _{.1} = 25 °C	0.77		
Maximum forward voltage drop per leg	V _{FM} ⁽¹⁾	60 A	1j=25 C	0.92	v	
See fig. 1	V _{FM} (1)	30 A	T 105 %C	0.64	V	
		60 A	T _J = 125 °C	0.76		
Maximum reverse leakage current per leg	I _{RM} ⁽¹⁾	T _J = 25 °C	V Datad V	0.3	mA	
See fig. 2	IRM (')	T _J = 125 °C	V _R = Rated V _R	25	IIIA	
Threshold voltage	V _{F(TO)}	T T manyimum		0.38	V	
Forward slope resistance	r _t	$T_J = T_J$ maximum		5.75	mΩ	
Maximum junction capacitance per leg	C _T	V _R = 5 V _{DC} (test signal range 100 kHz to 1 MHz) 25 °C		1300	pF	
Typical series inductance per leg	L _S	Measured lead to lead 5 mm from package body		7.5	nΗ	
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs	

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction and storage temperature range	T _J , T _{Stg}		- 55 to 175	°C		
Maximum thermal resistance, junction to case per leg	В	DC operation See fig. 4	0.8			
Maximum thermal resistance, junction to case per package	R _{thJC}	DC operation	0.4	°C/W		
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth and greased	0.25			
Approximate weight			6	g		
Approximate weight			0.21	OZ.		
Mounting torque	mum		6 (5)	kgf · cm		
Mounting torque — maxir	num		12 (10)	(lbf \cdot in)		
Marking device		Case style TO-247AC (JEDEC)	63CP0	Q100G		

Vishay Semiconductors

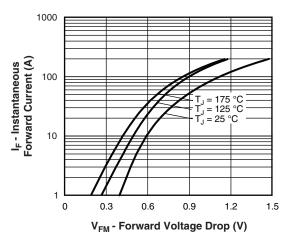


Fig. 1 - Maximum Forward Voltage Drop Characteristics

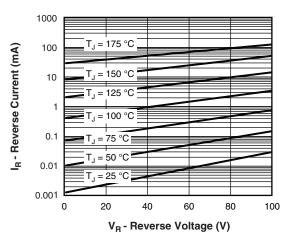


Fig. 2 - Typical Values of Reverse Current vs.
Reverse Voltage

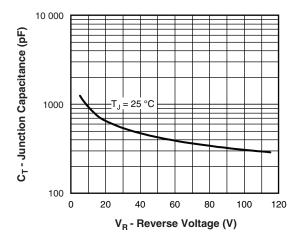


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

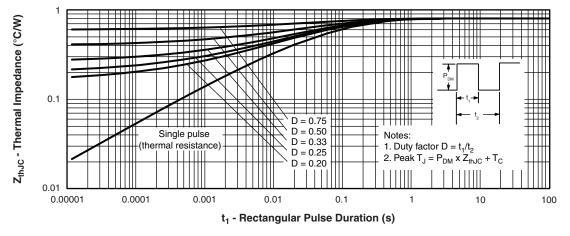


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

www.vishay.com

Vishay Semiconductors

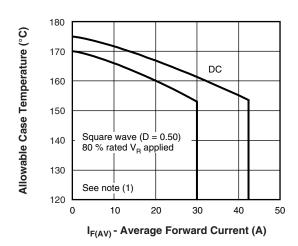


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

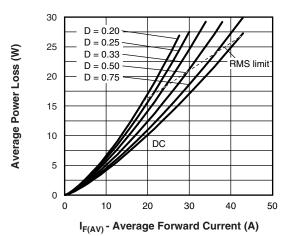


Fig. 6 - Forward Power Loss Characteristics

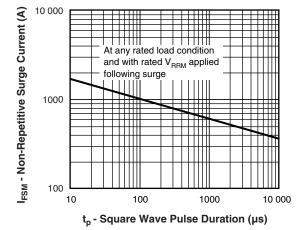


Fig. 7 - Maximum Non-Repetitive Surge Current

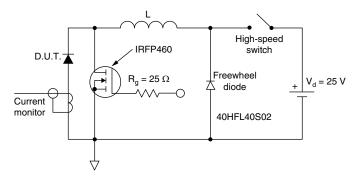


Fig. 8 - Unclamped Inductive Test Circuit

Note

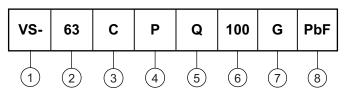
(1) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{th,JC}$; $Pd = Forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D)$ (see fig. 6); $Pd_{REV} = Inverse power loss = V_{R1} \times I_R (1 - D)$; I_R at $V_{R1} = 80$ % rated V_R

VS-63CPQ100GPbF, VS-63CPQ100G-N3

Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code



- Vishay Semiconductors product

2 - Current rating (60 A)

3 - Circuit configuration:

C = Common cathode

4 - Package:

P = TO-247

5 - Schottky "Q" series

6 - Voltage rating (100 V)

7 - G = Schottky generation

8 - Environmental digit

• PbF = Lead (Pb)-free and RoHS compliant

• -N3 = Halogen-free, RoHS compliant, and totally lead (Pb)-free

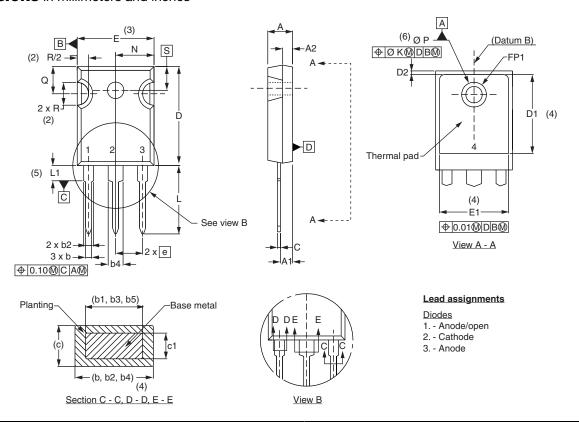
ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-63CPQ100GPbF	25	500	Antistatic plastic tube			
VS-63CPQ100G-N3	25	500	Antistatic plastic tube			

LINKS TO RELATED DOCUMENTS				
Dimensions <u>www.vishay.com/doc?95223</u>				
Dort marking information	TO-247AC PbF	www.vishay.com/doc?95226		
Part marking information	TO-247AC -N3	www.vishay.com/doc?95007		



Vishay Semiconductors

DIMENSIONS in millimeters and inches



SYMBOL	MILLIN	IETERS	INC	INCHES		
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	
Α	4.65	5.31	0.183	0.209		
A1	2.21	2.59	0.087	0.102		
A2	1.50	2.49	0.059	0.098		
b	0.99	1.40	0.039	0.055		
b1	0.99	1.35	0.039	0.053		
b2	1.65	2.39	0.065	0.094		
b3	1.65	2.37	0.065	0.094		
b4	2.59	3.43	0.102	0.135		
b5	2.59	3.38	0.102	0.133		
С	0.38	0.86	0.015	0.034		
c1	0.38	0.76	0.015	0.030		
D	19.71	20.70	0.776	0.815	3	
D1	13.08	-	0.515	-	4	

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
D2	0.51	1.30	0.020	0.051	
E	15.29	15.87	0.602	0.625	3
E1	13.72	-	0.540	-	
е	5.46	BSC	0.215	BSC	
FK	2.54		0.0	10	
L	14.20	16.10	0.559	0.634	
L1	3.71	4.29	0.146	0.169	
N	7.62	BSC	0.3		
ΦР	3.56	3.66	0.14	0.144	
ФР1	1	6.98	-	0.275	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	1.78	0.216	
S	5.51 BSC		0.217	BSC	

Notes

- ⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- (5) Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- (7) Outline conforms to JEDEC outline TO-247 with exception of dimension c

Legal Disclaimer Notice



Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

Material Category Policy

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.

Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Vishay documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.

Revision: 02-Oct-12 Document Number: 91000